

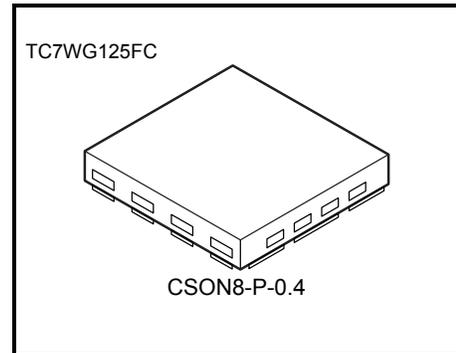
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WG125FC

Dual Bus Buffer with 3-STATE Output

Features

- High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$
at $V_{CC} = 3 \text{ V}$
- High-speed operation: $t_{pd} = 2.5 \text{ ns (typ.)}$
at $V_{CC} = 3.3 \text{ V}, 15\text{pF}$
- Operating voltage range: $V_{CC} = 0.9\sim 3.6 \text{ V}$
- 5.5-V tolerant inputs
- 3.6-V power down protection outputs



Weight: 0.002 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V_{CC}	-0.5~4.6	V
DC input voltage	V_{IN}	-0.5~7.0	V
DC output voltage	V_{OUT}	-0.5~4.6 (Note 1)	V
		-0.5~ $V_{CC} + 0.5$ (Note 2)	
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	-20 (Note 3)	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC}/GND current	I_{CC}	± 100	mA
Power dissipation	P_D	150 (Note 4)	mW
Storage temperature	T_{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0 \text{ V}$

Note 2: High or Low State.

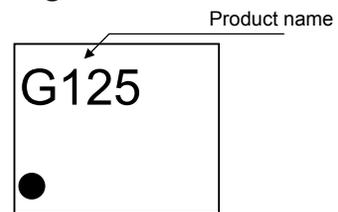
I_{OUT} absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND$

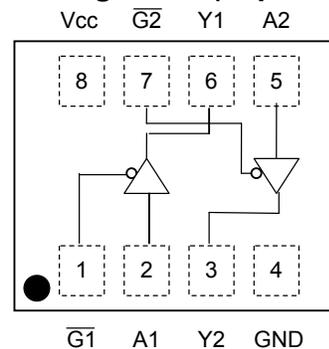
Note 4: Mounted on an FR4 board.

(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 11.56 mm²)

Marking



Pin Assignment (top view)

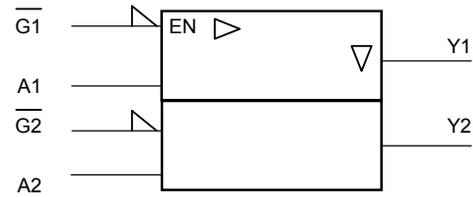


Truth Table

Inputs		Outputs
\overline{G}	A	Y
H	X	Z
L	L	L
L	H	H

X: Don't Care
Z: High impedance

IEC Logic Symbol



Operating Ranges

Characteristics	Symbol	Value	Unit
Power supply voltage	V_{CC}	0.9~3.6	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~3.6 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output Current	I_{OH}/I_{OL}	± 8.0 (Note 7)	mA
		± 4.0 (Note 8)	
		± 3.0 (Note 9)	
		± 1.7 (Note 10)	
		± 0.3 (Note 11)	
		± 0.02 (Note 12)	
Operating temperature	T_{opr}	-40~85	$^{\circ}C$
Input rise and fall time	dt/dV	0~10 (Note 13)	ns/V

Note 5: $V_{CC} = 0 V$

Note 6: High or Low state.

Note 7: $V_{CC} = 3.0\sim 3.6 V$

Note 8: $V_{CC} = 2.3\sim 2.7 V$

Note 9: $V_{CC} = 1.65\sim 1.95 V$

Note 10: $V_{CC} = 1.4\sim 1.6 V$

Note 11: $V_{CC} = 1.1\sim 1.3 V$

Note 12: $V_{CC} = 0.9 V$

Note 13: $V_{IN} = 0.8\sim 2.0 V, V_{CC} = 3.0 V$

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit		
				V _{CC} (V)	Min	Typ.	Max	Min		Max	
Input voltage	High level	V _{IH}	—	0.9	V _{CC}	—	—	V _{CC}	—	V	
				1.1~1.3	V _{CC} × 0.7	—	—	V _{CC} × 0.7	—		
				1.4~1.6	V _{CC} × 0.65	—	—	V _{CC} × 0.65	—		
				1.65~1.95	V _{CC} × 0.65	—	—	V _{CC} × 0.65	—		
				2.3~2.7	1.7	—	—	1.7	—		
				3.0~3.6	2.0	—	—	2.0	—		
	Low level	V _{IL}	—	0.9	—	—	GND	—	GND		
				1.1~1.3	—	—	V _{CC} × 0.3	—	V _{CC} × 0.3		
				1.4~1.6	—	—	V _{CC} × 0.35	—	V _{CC} × 0.35		
				1.65~1.95	—	—	V _{CC} × 0.35	—	V _{CC} × 0.35		
				2.3~2.7	—	—	0.7	—	0.7		
				3.0~3.6	—	—	0.8	—	0.8		
Output voltage	High level	V _{OH}	V _{IN} = V _{IL} or V _{IH}	I _{OH} = -0.02 mA	0.9	0.75	—	—	0.75	—	V
				I _{OH} = -0.3 mA	1.1~1.3	V _{CC} × 0.75	—	—	V _{CC} × 0.75	—	
				I _{OH} = -1.7 mA	1.4~1.6	V _{CC} × 0.75	—	—	V _{CC} × 0.75	—	
				I _{OH} = -3.0 mA	1.65~1.95	V _{CC} -0.45	—	—	V _{CC} -0.45	—	
				I _{OH} = -4.0 mA	2.3~2.7	2.0	—	—	2.0	—	
				I _{OH} = -8.0 mA	3.0~3.6	2.48	—	—	2.48	—	
	Low level	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 0.02 mA	0.9	—	—	0.1	—	0.1	
				I _{OL} = 0.3 mA	1.1~1.3	—	—	V _{CC} × 0.25	—	V _{CC} × 0.25	
				I _{OL} = 1.7 mA	1.4~1.6	—	—	V _{CC} × 0.25	—	V _{CC} × 0.25	
				I _{OL} = 3.0 mA	1.65~1.95	—	—	0.45	—	0.45	
				I _{OL} = 4.0 mA	2.3~2.7	—	—	0.4	—	0.4	
				I _{OL} = 8.0 mA	3.0~3.6	—	—	0.4	—	0.4	
Input leakage current		I _{IN}	V _{IN} = 0~5.5V	0~3.6	—	—	±0.1	—	±1.0	μA	
3-state output off-state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0~3.6V	0.9~3.6	—	—	1.0	—	10.0	μA	
Power off leakage current		I _{OFF}	V _{IN} = 5.5V or V _{OUT} = 3.6V	0.0	—	—	1.0	—	10.0	μA	
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND	3.6	—	—	1.0	—	10.0	μA	

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit			
			V _{CC} (V)	Min	Typ.	Max	Min		Max		
Propagation delay time	t_{pLH} t_{pHL}	C _L = 10 pF, R _L = 1 MΩ	0.9	—	18.3	—	—	ns			
			1.1~1.3	—	9.4	18.4	1.0		34.9		
			1.4~1.6	—	5.5	8.5	1.0		10.7		
			1.65~ 1.95	—	4.2	6.2	1.0		6.7		
			2.3~2.7	—	2.8	3.9	1.0		4.4		
			3.0~3.6	—	2.3	3.1	1.0		3.7		
		C _L = 15 pF, R _L = 1 MΩ	0.9	—	21.2	—	—		—		
			1.1~1.3	—	10.7	21.5	1.0		38.0		
			1.4~1.6	—	6.1	9.3	1.0		11.9		
			1.65~ 1.95	—	4.7	6.9	1.0		7.1		
			2.3~2.7	—	3.1	4.4	1.0		5.0		
		C _L = 30 pF, R _L = 1 MΩ	0.9	—	30.5	—	—		—		
			1.1~1.3	—	14.9	30.0	1.0		58.1		
			1.4~1.6	—	8.2	13.2	1.0		16.6		
			1.65~ 1.95	—	6.1	9.2	1.0		9.9		
			2.3~2.7	—	4.1	5.7	1.0		6.1		
		Output enable time	t_{pZL} t_{pZH}	C _L = 10 pF, R _L = 100 kΩ	0.9	—	24.0		—	—	ns
					1.1~1.3	—	11.8		22.5	1.0	
C _L = 10 pF, R _L = 5 kΩ	1.4~1.6			—	6.8	10.4	1.0	12.0			
	1.65~ 1.95			—	5.1	7.3	1.0	8.1			
	2.3~2.7			—	3.4	4.6	1.0	5.3			
	3.0~3.6			—	2.5	3.4	1.0	3.9			
C _L = 15 pF, R _L = 100 kΩ	0.9			—	26.6	—	—	—			
	1.1~1.3			—	13.0	25.0	1.0	41.9			
C _L = 15 pF, R _L = 5 kΩ	1.4~1.6			—	7.4	11.4	1.0	13.4			
	1.65~ 1.95			—	5.5	7.9	1.0	8.5			
	2.3~2.7			—	3.7	4.9	1.0	5.5			
	3.0~3.6			—	3.0	4.1	1.0	4.6			
C _L = 30 pF, R _L = 100 kΩ	0.9			—	36.4	—	—	—			
	1.1~1.3			—	17.9	35.8	1.0	59.1			
C _L = 30 pF, R _L = 5 kΩ	1.4~1.6			—	9.8	15.3	1.0	17.8			
	1.65~ 1.95			—	7.2	10.5	1.0	11.2			
	2.3~2.7			—	4.5	5.9	1.0	6.6			
	3.0~3.6			—	3.6	4.6	1.0	5.3			

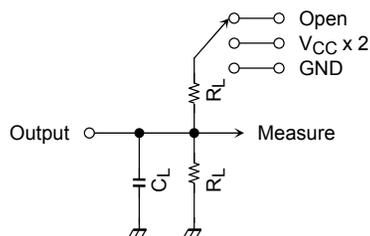
Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit	
			V _{CC} (V)	Min	Typ.	Max	Min		Max
Output disable time	t _{pLZ} t _{pHZ}	C _L = 10 pF, R _L = 100 kΩ	0.9	—	168.6	—	—	—	ns
			1.1~1.3	—	9.5	18.4	1.0	25.2	
		C _L = 10 pF, R _L = 5 kΩ	1.4~1.6	—	7.5	9.5	1.0	10.6	
			1.65~ 1.95	—	7.1	8.7	1.0	9.6	
			2.3~2.7	—	6.8	7.9	1.0	8.8	
			3.0~3.6	—	6.5	7.5	1.0	8.4	
		C _L = 15 pF, R _L = 100 kΩ	0.9	—	201.8	—	—	—	
			1.1~1.3	—	10.5	19.8	1.0	27.6	
		C _L = 15 pF, R _L = 5 kΩ	1.4~1.6	—	9.0	10.4	1.0	12.3	
			1.65~ 1.95	—	8.5	9.7	1.0	10.6	
			2.3~2.7	—	7.9	8.8	1.0	10.3	
			3.0~3.6	—	7.6	8.3	1.0	9.5	
		C _L = 30 pF, R _L = 100 kΩ	0.9	—	251.5	—	—	—	
			1.1~1.3	—	14.1	23.8	1.0	31.9	
		C _L = 30 pF, R _L = 5 kΩ	1.4~1.6	—	13.5	14.5	1.0	16.0	
			1.65~ 1.95	—	12.7	14.3	1.0	15.0	
			2.3~2.7	—	12.2	14.1	1.0	14.7	
			3.0~3.6	—	11.9	13.8	1.0	14.4	
3.0~3.6	—		11.9	13.8	1.0	14.4			
Input capacitance	C _{IN}	—	3.6	—	3	—	—	pF	
Power dissipation capacitance	C _{PD}	(Note 14)	0.9 ~ 3.6	—	10	—	—	—	pF

Note 14: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$$

AC Characteristics Measurement Circuit



Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	V _{CC} x 2
t _{pHZ} , t _{pZH}	GND

Figure1 t_{pLH}, t_{pHL}

AC Waveforms

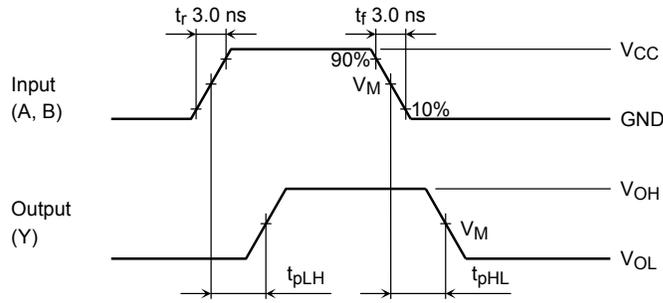


Figure2 t_{pLH} , t_{pHL}

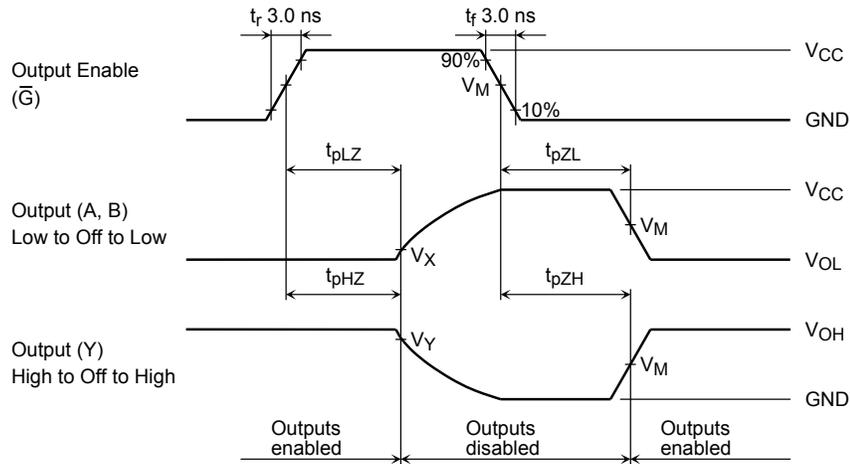


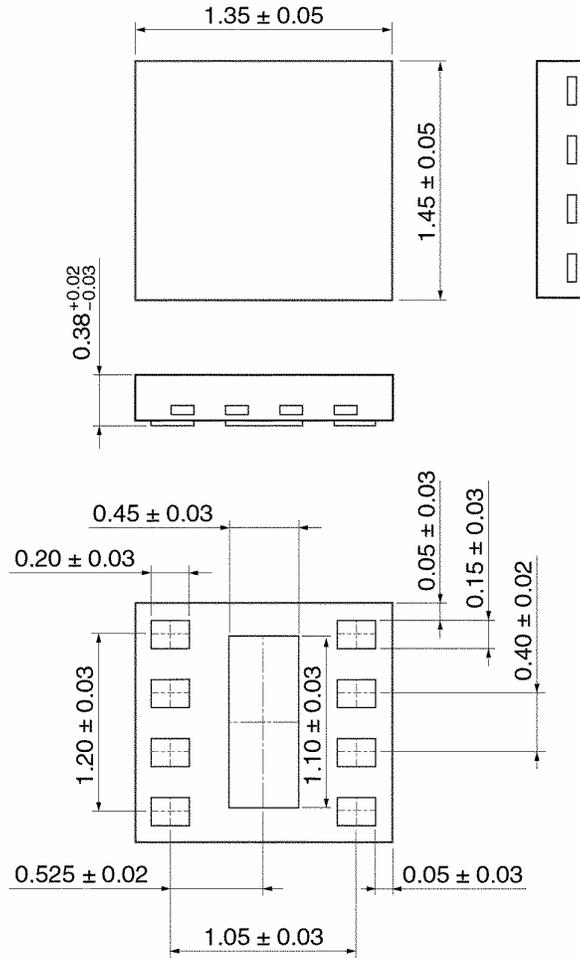
Figure3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

UNIT	V_{CC}					
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	$1.8 \pm 0.15 \text{ V}$	$1.5 \pm 0.1 \text{ V}$	$1.2 \pm 0.1 \text{ V}$	0.9 V
V_M	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$
V_X	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.1 \text{ V}$	$V_{OL} + 0.1 \text{ V}$	$V_{OL} + 0.1 \text{ V}$
V_Y	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.1 \text{ V}$	$V_{OH} - 0.1 \text{ V}$	$V_{OH} - 0.1 \text{ V}$

Package Dimensions

CSON8-P-0.4

Unit: mm



Weight : 0.002 g (Typ.)

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20070701-EN GENERAL

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